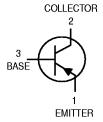
# **Amplifier Transistors PNP Silicon**



## **LA733P**



#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	VCEO	-50	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current — Continuous	IC	-100	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	350 2.8	mW mW/°C
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	1.0 8.0	Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	125	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = -1.0 mAdc, I <sub>B</sub> = 0)	V(BR)CEO	<b>-</b> 50	-	Vdc
Collector-Base Breakdown Voltage (I <sub>C</sub> = -10 μAdc, I <sub>E</sub> = 0)	V(BR)CBO	-60	1	Vdc
Emitter-Base Breakdown Voltage (I <sub>E</sub> = -10 μAdc, I <sub>C</sub> = 0)	V(BR)EBO	-5.0	1	Vdc
Collector–Emitter Leakage Current (V <sub>CB</sub> = -60 Vdc)	<sup>I</sup> CBO	_	-100	nAdc
Emitter-Base Leakage Current (VEB = -5.0 Vdc, IC = 0)	<sup>I</sup> EBO	_	-100	nAdc



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### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS	•	•	•	•
DC Current Gain (IC = $-1.0$ mAdc, VCE = $-6.0$ Vdc)	hFE	200	400	_
Collector-Emitter Saturation Voltage (IC = -10 mAdc, IB = -1.0 mAdc)	VCE(sat)	_	-0.3	Vdc
Base – Emitter Saturation Voltage (I <sub>C</sub> = -10 mAdc, I <sub>B</sub> = -1.0 mAdc)	V <sub>BE(sat)</sub>	_	-0.9	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = -1.0 mAdc, V <sub>CE</sub> = -6.0 Vdc)	V <sub>BE(on)</sub>	-0.55	-0.68	Vdc
DYNAMIC CHARACTERISTICS	•		•	•
Current-Gain — Bandwidth Product (IC = -10 mAdc, V <sub>CE</sub> = -6.0 Vdc, f = 20 MHz)	fT	100	450	MHz
Common–Base Output Capacitance (V <sub>CB</sub> = -60 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	_	7.0	pF
Noise Figure (IC = $-0.3$ mAdc, VCE = $-6.0$ Vdc,RG = $10$ k $\Omega$ , f = $100$ Hz)	NF	_	18	dB
Small–Signal Current Gain ( $I_C = -2.0 \text{ mAdc}$ , $V_{CE} = -5.0 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )	h <sub>fe</sub>	60	_	_

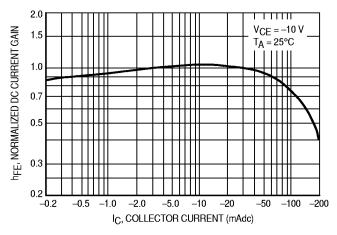


Figure 1. Normalized DC Current Gain

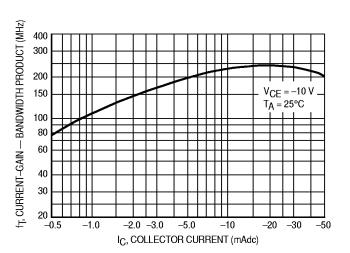


Figure 3. Current-Gain — Bandwidth Product

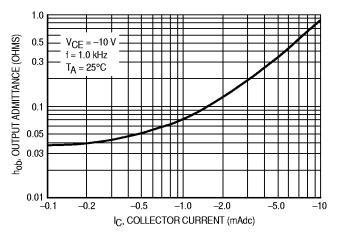


Figure 5. Output Admittance

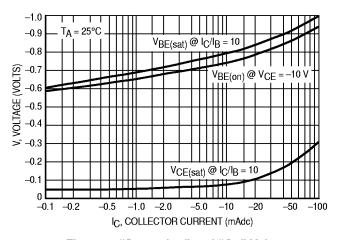


Figure 2. "Saturation" and "On" Voltages

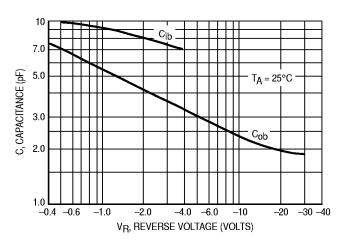


Figure 4. Capacitances

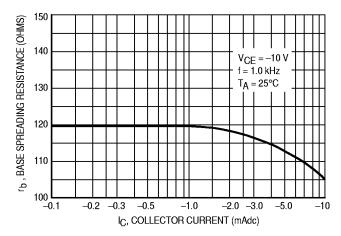
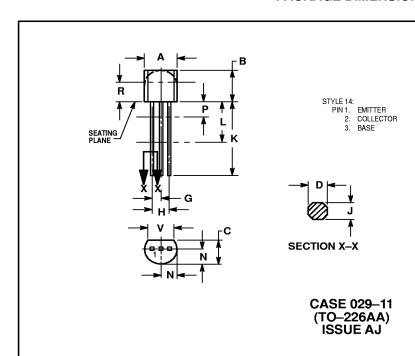


Figure 6. Base Spreading Resistance

#### PACKAGE DIMENSIONS



- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R 3. IS UNCONTROLLED.

  4. LEAD DIMENSION IS UNCONTROLLED IN P AND
- BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
в	0.170	0.210	4.32	5.33
O	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Ξ	0.095	0.105	2.42	2.66
-	0.015	0.020	0.39	0.50
K	0.500		12.70	l
L	0.250		6.35	
z	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	_

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